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### Description

### BACKGROUND OF THE INVENTION

This invention relates to an optical information carrier, a process for preparing the same as well as an optical card comprising the same.

Heretofore, a magnetic material has been mainly used as a recording material for information carriers embedded in cards such as a credit card and a bank card. In the case of this magnetic material, recording and readout of information can be readily carried out. However, the alternation of information is readily to carried out, and it is impossible to carry out high density recording.

In order to solve such problems, there has been proposed an optical recording material wherein a photosensitive material is imagewise exposed to form light transmissive portions and a light screening portions to write information in the photosensitive material, and this information is read out by the difference optical transmittancy. When such an optical recording material is embedded as an information carrier in a card substrate to use it as a recording material for a card, there are the following problems:

(a) In many cases, various printing compositions are applied to the surface of the card substrate, and therefore preferably the card substrate is opeque, However, in order to embed the optical recording material as described shows, it is necessary that the substrate exhibits allosat partially light transmission properties. This issimificantly disadvartapeous from the standpoint of the production of the card.

(b) in the case of the recording material as described above, it is difficult to sufficiently increase the difference in light transmission properties at the light transmissive portions and the light screening portions. Further, when the written information is intended to be read by the difference in transmittancy, soil at the surface of the card greatly affects readout.

Accordingly, an attempt has been made to intend to read out information by the difference in optical reflectivity rether than transmittancy. For example, there have been proposed cards having a recording layer wherein silver particles are dispersed a gelatin matrix. Writing of information in the recording layer is carried out by irradiating the recording layer with a laser beam to form recording pits. The recording layer can be confined to a coating process, and uniform reflectivity can be obtained over a wide region of wavelength by using silver. Furthermore, it is possible to apply to a record playback apparatus wherein a laser beam having various wavelengths is used. However, when recording is carried out by a photographic process, it is difficult to simultaneously improve optical reflection and definition. For example, when the development time is increased, optical reflection is improved, but recording portions (exceeded profines) tend to increase and definition may be lowered. On the contrary, when the development time is shortened, as findition is improved, but light reflection may become poor. When readout is carried out, a contrast be between recorded portion and non-recorded option in and non-recorded option in and non-recorded option in and non-recorded option in and non-recorded option is not clear.

Further, there has also been provided a so-called heat mode recording material wherein a recording layer of recording material is Irradiated with an energy beam such as a laser beam in the form of spots to change the state of part of the recording layer thereby recording. Thin films of metals such as tellurium and bismuth, thin films of organic compounds such as polystyrene and nitrocealtuses, films of tellurium low oxides (phase transition) or the like are used as the recording layer for use in the heat mode recording material. These recording materials do not require development treatment after writing of information, and so-called DRAW (direct read after writip media. It is possible to carry out lipth density recording, and it is also possible to carry out an additional writing. Accordingly, it is expected that uses as recording materials for discs or cards be increased.

Among these heat mode recording materials, he most widely used recording material is one wherein a thin film of metals such as tellurium and bismuth is vapor deposited on a substrate. In this recording material, writing of information is carried out by irradiating the metallic thin film with an energy beam such as a laser beam in the form of spots to remove the metal of Irradiated portions by vaporization or fusing thereby to form pits. Readout of information is carried out by Irradiating the recording portion with a readout set in the recording portion is carried out by Irradiating the recording portions and metallic thin film which are non-recording portions. In writing information, in addition to the formation of the recording pits which correspond to information per set be read out, it is necessary to write in the recording layer a tracking which corresponds to a guide groove for light as well as preformatting for specifying the noist to be read out.

However, metals such as tellurium and bismuth from which the recording layer is produced have toxicity to some extent, and therefore full care must be taken in handling. Further, the formation of pits by irradiation of an energy beam such as a laser beam requires high control technology. Furthermore, the pit formation steps are complicated and therefore the cost is not always low. Accordingly, if there is developed

a recording material wherein a tracking corresponding to a guide groove for light as well as preformating for specifying pits to be read out can be inexpensively formed in a large scale by simple processes other than laser beam irradiation, it is expected that such a recording material has extremely high usefulness.

On the other hand, there have been proposed cards having a recording layer as an information carrier swherein silver particles are dispersed in a gelatin matrix. Writing of information in this recording layer is carried out by irradiating the recording layer with a laser beam to form pits. The recording layer can be continuously produced by a coating process, and the use of silver affords uniform reflectivity over broad wavelength regions. Further, it is possible to apply to record playback apparatus wherein a laser beam having various wavelength regions is used. However, such a recording layer is made of silver, and therefore the cost is high. Further, it is difficult to stably and inexpensively produce and supply due to inductation of silver price. Furthermore, the pattern formation and development treatment must be carried out in a dark place in certain cases.

From document EP-A1-0 095 821, a medium for recording optically readable Information has come to be known. The medium comprises a transparent substrate layer, a semi-reflective recording layer of a material which can melt, atomize or evaporate under the influence of light, and a separating layer. On the other side of the separating layer, a full-reflecting layer is formed. Recording is made by forming a pattern of wholes extending through the complete brickness of both the recording layer and the separating layer. The full-reflective layer remains uniformly reflective.

### 20 SUMMARY OF THE INVENTION

The present invention aims at the solution of the problems accompanying the prior art while achieving the following objects.

(a) One object is to provide an optical information carrier wherein it is possible to carry out high density recording and the atternation of written information is difficult; an optical card; as well as a process for preparing the optical information carrier.

(b) Another object is to provide an optical information carrier wherein the written information can be read out on a basis of the difference in light reflectivity; an optical card; as well as a process for preparing the optical information carrier.
(c) A further object is to provide an optical information carrier wherein writing of information in a

recording layer can be carried out by mass productive processes such as imagewise exposure without using any laser beam; an optical card; as well as a process for proparing the optical information carrier. (d) A further object is provide an optical information carrier wherein writing of tracking as well as preformatting required for readout of recording pits corresponding to information per se to be read out as on be formed without any irradiation of an energy beam and, therefore, the productions respect and samplified and a mass production and a decrease in cost can be achieved; an optical card; as well as a

process for producing the optical information carrier.

These objects are solved according to the invention by an optical information carrier as claimed with claim 1. Subclaims 2 to 11 worlbit further improvements to the subject-matter of claim 1. Claim 12 exhibits a process for preparing an optical information carrier according to claim 1. Moreover, sub-claims 13 to 16 give further improvements to the process claimed with claim 12. Finally, an optical card comprising an optical information carrier according to the invention is claimed in claim 17.

An optical information carrier according to the present invention relates to (i) a substrate, (ii) a recording layer provided on the substrate, the recording layer consisting of light transmissive portion and light screening portions, and (iii) a reflective metallic thin film layer provided on the recording layer, wherein readout of information written in the recording layer and the metallic thin film layer is carried out by irradiating the optical information carrier with a record playback light from the recording layer-free side of the substrate.

An optical information carrier of a first processing state according to the present invention comprises (I) so a substrate, (II) a first recording layer provided on the substrate, the first recording layer provided on the first transmissive portions and filly a second recording layer provided on the first recording layer, the second recording layer consisting of a reflective thin film layer, wherein information is written in the second layer by irradiating the second recording layer with an energy beam in the form of spots, and wherein readout of the written information is carried out by exposing to a record playback light set of the second recording layer the optical information carrier of the first second recording layers. The optical information carrier of the first embodiment is in such a state that writing of information in the second recording layer is not yet carried out.

An optical information carrier of a second processing state according to the present invention comprises (i) a substrate, (ii) a first recording layer provided on the substrate, the first recording layer consisting of

light transmissive portions and light screening portions, and (III) a second recording layer provided on the first recording layer, the second recording layer consisting of a reflective metallic thin film layer having recording pits formed therein, wherein readout of the witten information is carried out by exposing to a record playback light from the side provided with no said first and second recording layers. The optical information carrier of the second embodiment is in such a state that writing of information in the second recording layer has been already certified out.

In a third processing state of an optical information carrier according to the present invention, any information cannot be written in said metallic thin film layer and readout of information written in said proording layer is carried out by irradiating the optical Information carrier with a record playback light from recording layer-free side of the substrate.

# BRIEF DESCRIPTION OF THE DRAWINGS

Figure 1 is a sectional view of an optical recording material according to the present invention;

Figures 2 through 6 are sectional views of embodiments of an optical card according to the present invention.

Figure 7 is a schematic view of an optical card having bars of one type according to the present

Figure 8 is a schematic view of an optical card having bars of another type according to the present invention; and

Figure 9 is a plan view of an optical card according to the present invention.

# DETAILED DESCRIPTION OF THE INVENTION

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s Preferred embodiments of an optical recording material according to the present invention will now be described with reference to the drawing.

An optical recording material 1 according to the present invention comprises a substate 2; a recording layer 5 provided on the substrate 2; the recording layer consisting of light transmissive portions 3 and light screening portions 4; and a reflective metallic thin film layer 6 provided on the recording layer 5.

According to one embodiment, said recording layer is a first recording layer and said metallic thin film layer is a second recording layer capable of writing information by Irradiating it with an energy beam.

According to another embodiment, said recording layer is a first recording layer and said metallic thin film layer is a second recording layer having substantially circular, elliptic or rectangular recording pits formed thresh.

According to another embodiment, information can be written in said recording layer and said metallic thin film layer is not capable of writing information.

Examples of the substrate 2 which can be used in the present invention are any type of materials such as glasses, ceramics, papers, plastic films, woven tabrics and non-woven fabrics. From the standpoints of productivity and smoothness, glasses and plastic films are preferred. Examples of plastics which can be 40 used in the present invention are cellulose derivatives, polyseter resins, polysurider resins, polysurider resins, polymetry learned productions are polysurider resins, polysurider resins, polymetry learned regins, polysurider resins, polymetry learned regins and cellulose triscotate resins. From the standpoints of transparency and smoothness, cellulose triscotate, polysuridulate, polycarbonate, acryl polymetry learned present and the like are particularly preferred. The substrate wind the film of the present plasma treatment and primer treatment and primer treatment and primer treatment and primer treatment.

The first recording layer 5 comprises light transmissive portions 3 and light screening portions 4. The first recording layer 5 is formed, for exemple, by imagewise exposing a photosensitive material wherein unexposed portions exhibit light transmission properties and exposed portions exhibit light screening properties, and then developing. Optionally, the first recording layer may be formed by imagewise exposing a photosensitive material wherein unexposed portions exhibit light transmission properties, and then developing.

The photosensitive material comprises, for example, (a) a transparent resin as a binder, (b) a photodecomposable development restrainer having a diazo or azido group, and (c) a metal complex so compound or metal compound which is reduced to form metal developing nuclei. This material is called a non-eliver photosensitive material, in such photosensitive materials, the photodecomposable development restrainer having a diazo or azido group is present in an amount of from 1 to 100 parts by weight, preferably from 20 to 50 parts by weight of the transparent resin as the binder, and

the metal complex compound or metal compound which is reduced to form a metal developing nucleus is present in an amount of from 0.1 to 100 parts by weight, preferably from 1 to 10 parts by weight per 100 parts by weight of the transparent resin as the binder. While the development restrainer and the metal complex compound or metal compound described above are dissolved or dispersed in the transparent resin as the binder, they are preferably dissolved therein.

Any of lipophilic or hydrophilic transparent resins can be used as the transparent resin. The lipophilic transparent resins include resins having an ester group such as polyvinyl acetate resins, vinyl acetate/acytic ester copolymer resins, acrylic acidvinyl acetate copolymer resins, ethylene/vinyl acetate copolymer resins; resins having a hydroxyl group such as cellulose acetate; modified vinyl acetate resins having a chapoval oroup or a subfonate orough.

Further, the incorporation of cellulose derivatives such as nitrocellulose wherein optical recording characteristics are changed in a heat mode, into these lipophilic transparent resins is effective for increasing

Examples of hydrophilic transparent resins for use herein are natural polymeric materials such as a gelatin, casein, glue, gum arabic, and shellac; carboxymethyl cellulose; ggg albumin; and synthetic resins such as polyminyl alcohol (partially saponified polyminyl acetate), polyacrylic acid, polyacrylamide, polywinyl pyrrolidone, polywithylene oxide, and maleic anhydride copolymer. Other resins can be used so long as they are water-soluble or hydrophilic resins. Preferably, the hydrophilic transparent resin as the binder has such a hydrophilicly that, in contacting a transparent resin-based photosensitive material layer with a physical developing solution, the physical developing solution can penetrate the photosensitive material layer to carry out physical development.

Low molecular weight compounds such as nitrocellulose wherein optical recording characteristics are changed in a heat mode can be dissolved in ethanol and the resulting solution is effectively incorporated in the hydrophilir cesin described above.

The compound having a diazo or azido ground is used as the development restrainer. Preferred compounds having a diazo group are zinc chloride double salts or borofluorides having a diazo group, and the condensation product of these compounds and paraformadelryde. Specific examples of the compounds which can be used in the invention are zinc chloride double salts having a diazo group such as PNN-diethylaminobenzenediazonium zinc chloride double salt, 4-morpholino-2,5-diethoxybenzenediazonium zinc chloride double salt, 4-morpholino-2,5-diethoxybenzenediazonium zinc chloride double salt, 4-ferrentpoxybenzenediazonium zinc chloride double salt salt postanium zinc chloride double salt salt postanium zinc chloride double salt salt

zinc chloride in such compounds is replaced by borofluoride, sulfate and phosphate groups.

Examples of the compounds having an azido group which can be used in the present invention are pazidosecephenone, 4,4"diazidochalcone, 2,2-bis(4"azidobenzal)-acetone, 2,8-bis(4"azidobenzal)-t-methylcyclohexanone, 2,8-bis(4"azidobenzal)-t-methylcyclohexanone, 2,8-bis(4"azidobenzal)-t-methylcyclohexanone, 2,8-bis(4"azidostyny)-acetone, and azidopyrene.

Other compounds can be also used so long as they have a diazo or azido group. The above compounds having a diazo or azido group can be also optionally used in combination of two or more compounds.

When the compound having a diazo group is used, it is preferable to use a stabilizer which stabilize the compound. Organic carboxylic acids and organic sulfonic acids can be used as the stabilizer. It is practically preferable to use p-tolusnesulfonic acid or the like.

The metal complex compound or metal compounds which are reduced to form metal development nuclei will be described hereinafter. Complex compounds of metals such as palladium, gold, silver, platinum and copper are used as the metal complex compounds which are reduced to form metal development nuclei. The conventionally known figands can be used as the ligands which are electron donors against these metals. Specific examples of the metal complex compounds for use herein are as follows: bisse (ethylenediamine) palladium (II) salt, dichloroethylenediaminepalladium (II) salt, dichloro (ethylenediamine) platinum (V) salt, tetrachkorodiaminepaltinum (IV) salt, dichlorofischtylenediamine) platinum (IV) salt, tetraethylamnonium coopper (III) salt, dichlorobis(ethylenediamine) platinum (IV) salt, tetraethylamnonium coopper (III) salt, dichlorobis(ethylenediamine) coopper (III) salt.

When so-called chelating agents which coordinate at two or more positions to form a ring structure are used as the ligands which form the metal complex compounds, the stability of the resulting metal complex so compounds is high and therefore the use of such chelating agents is suitable. The chelating agents include primary, secondary and tertiary amines, oximes, imines, and ketones. Specific examples of suitable chilating agents for use herein are compounds such as dimethylglyoxime, dithizone, oxine, acetylacetone, glycine, ethylenoidamineletraceute caid, intiliotriacel icad and unrealidiacetic acid.

Preferred cheleting agent-containing metal complex compounds are bis(2,2\*-bipyridine) palladium (II) sait, bis(acetylacetanato) palladium (III) bis(N,N-diethylethylenediamine) copper (II) sait, bis(2,2\*-bipyridine) copper (II) sait, bis(1,10-phenanthroline) copper (II) sait, bis(dimethylglyoximato) copper (II), bis-(acetylacetonato) platinum (II).

Metal compounds such as-water-soluble salts such as chlorides and nitrates of metals such as epilladium, gold, silver, platinum and copper are used as the metal compounds which are reduced to form metal developing nuclei. Specific examples of suitable metal compounds are salts such as palladium chloride, silver nitrate and gold hydrogen tetrachloride contained in an activator solution for electroless platino. Of these palladium salts are carticularly ordered.

The components as described above, i.e., (a) the transparent resin as the binder, (b) the photodecomposable development restrainer having a diaze or azide group and (c) the metal complex compound or metal compound which is reduced to form metal developing nuclei are mixed with a solvent selected depending upon the transparent resin as the binder to prepare coating solution for forming a photosensitive material layer having a viscosity suitable for application, i.e., from 10 to 1000 certiplosise. This coating resolution for forming the photosensitive material layer is applied onto the substrate 2 to a film thickness of from 0.1 to 30 micrometers thereby to form a layer of photosensitive material.

A variety of solvents can be used as the solvents which dissolve the transparent resin as the binder.

When the hydrophilic transparent resin is used, water, water-miscible solvents or mixtures of water and water-miscible solvents such as lower alcohols, ketones, and ethers can be used. When the lipophilic transparent resin is used, solvents having high polarity such as methyl cellosolve, lower alcohols such as methyl alcohol, ethyl alcohol and isopropyl alcohol, ketones such as acetone and methyl ethyl ketone, and esters such as ethyl acetal and h-butyl acetale are preferably used.

When the hydrophilic transparent resin is used, it is desirable to carry out film-hardening treatment after formation of the photosensitive melerial layer in order to prevent the binder from eluting in the developing solution during physical development treatment. The film-hardening treatment can-be carried out, for example, by premixing the following compounds in the coating solution for forming the photosensitive meterial in an amount of from 0.1 to 50 parts per 100 parts of the transparent resin, or by applying an aqueous solution of the following solution onto the previously formed layer of photosensitive meterial.

Al compounds such as potesh alum and ammonium alum; Or compounds such as chromium alum and chromium sultate; aldehydes such as formaldehyde, glyvacal, glutaraldehyde, a-methylquitaradehyde, and succinaldehyde; diketones such as o-benzoquinone, p-benzoquinone, cyclohexane-1,2-dione, cyclopentane1,2-dione, discostyl. 2,5-pentanedione, 2,5-hexanedione, and 2,5-hexanedione; epoxides such as trigylcridylsocyanurate; acid anhydrides such as tetraphthally cilindice, and 44-diplenyimpethanedisullongly oldride; tannic acid, gallic acid, 2,4-dichloro-6-hydroxy-s-frazine, phosphorus compounds represented by the general formulae s; Ray-Roxy, (Rs/Ng-Ng-Ns-n

$$\binom{\text{CH}_2}{\binom{\text{CH}_2}{\text{CH}_2}}$$
N)<sub>2</sub>PR, and  $\binom{\text{CH}_2}{\binom{\text{CH}_2}{\text{CH}_2}}$ N)<sub>2</sub>POR,

and carbodiimide represented by the general formula: R-N = C = N-R\* wherein R is an alkyl group containing from 2 to 6 carbon atoms, R\* is a (CH<sub>2</sub>)<sub>2</sub>N\*\*(CH<sub>2</sub>)<sub>2</sub>X\*\* group, X is F or CI, and n is 1 or 2; resins such as styrene/maleic acid copolymer, viryl pyrnoidone/maleic acid copolymer, vinyl methyl ether/maleic acid copolymer, ethylene/maleic acid copolymer, methacrylic acid/methacrylonitrile copolymer, polymerhacrylamide and methacrylic ester copolymer; glutaric acid, succinic acid, malic acid, lactic acid, citric acid, spartic acid, glycolic acid, startor acid and the like.

The photosensitive material layer provided on the substrate 2 is Imagewise exposed and then developed to form a recording layer 5 consisting of light transmissive portions 3 which are unexposed portions and light screening portions 4 which are exposed portions. The imagewise exposure can be carried out, for example, via mask such as a photomask.

Also, an irradiation light can be focused in the form of a beam and the photosensitive layer can be directly irradiated with the focused light to form the light screening portions 4 in the form of patterns.

Image information derived from the light transmissive portions 3 and light screening portions 4 of the seconding layer 5 acts as a tracking and a preformat in reading out information.

At the exposed portions of the photosensitive material layer, the photodecomposable development restrainer having the diazo or azido group decomposes depending upon the amount of exposure to form a latent image. Any light source can be used as a light source used during exposure provided that the light source can decompose the compound having the diazo or azido group. Usually, an ultra-high pressure mercury vapor lamp is preferably used.

The latent image formed by the decomposition of the compound having the diazo or azido group by 5 means of the imagewise exposure as described above is brought into contact with an apueus solution of reducing agent to generate metallic developing nuclei. Art be unexposed portions, the development restrainer having the diazo or azido group is not decomposed and therefore no metallic developing nuclei are generated even if it is brought into contact with the aqueous solution of the reducing agent. Thus, the unexposed oothors remain as the ficit transmissive portions intact.

to Examples of suitable reducing agents for use herein are stannous chloride, stannous suitate, sodium boron hydride; borzane compounds such as dimethylamineborazane, diethylamineborazane, and trimethylamineborazane; borane compounds such as borane, diborane and methyldiborane; and hydrazine. Of these, an acidic stannous chloride solution, a stannous sulfate solution (weiss solution) and a commercially available sensitizer solution for electroless plating are particularly prelemed. In general, any reducing spent can be used provided that it is a strong reducing agent.

The metallic developing nuclei thus obtained are then brought into contact with a physical developing solution to reduce the metal contained in the physical developing solution. Thus, the metal deposits around the metallic developing nucleus described above to form light screening portions 4.

An aqueous solution containing a water-soluble reducible metallic salt and a reducing agent is as the physical developing solution in a cool state or a warm state as needed.

Water-soluble salts of nickel, cobalt, iron, the group VIb metals such as chromium, and the group Ib metals such as copper are used alone or in admixture as the reducible metallic salt. Once the physical development is carried out with a solution of a copper salt, and thereafter a stannous chloride or tin sulfate plating can be carried out to substitute it for the copper salt. Thus, it is possible to obtain a metallic layer of st fin or tin-copper. Of these, nickel, copper and tin are preferred from the standpoints of salery and storage properties. Unlike vapor deposition, a small amount of foreign metals and elements such as phosphorus and sulfur from the impurities of the raw material and plating stabilizers may be admixed. However, they do not substantially affect the characteristics of the optical recording material.

Specific examples of suitable water-soluble reducible metallic salts for use herein are heavy metal so haifdes such as cobaltous chloride, cobaltous lodide, ferrous bromide, terrous chloride, chromic bromide, chromic bromide, chromic bromide, chromic bromide, chromic suitate, cobaltous suitate, corbaltous suitate, chromic suitate, chard cupric suitate; heavy metal nitrates such as nickel nitrate, ferrous nitrate, cobaltous nitrate, chromic nitrate and cupric nitrate; and organic acid salts of metals such as ferrous acetate. Cobaltous acetate, cobaltous acetate. Cahonic acetate, and cupric formate.

It is preferable that these reducible heavy metal salts be present in the physical developing solution, for example, at a level of from 10 to 100 grams per liter.

Examples of the reducing agents for use herein are hypophosphorous acid, sodium hypophosphile, sodium boron hydride, hydrazine, formalin, diethylamineborane, borane, diborane, methydiborane, diborane, methydiborane, diborane, diborane, diborane, diborane, borazine, trebutylamineborazane, pyridineborane, 2,6-lutidineborane, ethylenediamineborane, hydrazinediborane, dimethylamineborane, phenylphosphineborane, dimethylamineborane, phenylarsineborane, dimethylamineborane, dimethylamineborane

It is preferable that these reducing agents be present in the physical developing solution, for example, at a level of from 0.1 to 50 grams per liter.

45 In order to prevent a heavy metal ion formed by the dissolution of the reducible heavy metal selt described above from percipitating as a hydroxide, one or more complexing agents selected from the group consisting of organic carboxylic acids such as monocarboxylic acids, dicarboxylic acids, hydroxycarboxylic acids such as malic acid and lactic acid, succinic acid, city aspetito acid, glycol acid, startaric acid, ethylenoclaiminetertazeable acid, glucoric acid, secharic acid and quintine acid can be incorporated in the sep hysical developing solution. It is preferable that these complaying agents be present in the physical developing solution, for example, at a level of from 1 to 100 grams per liter.

In order to improve the storage properties and operability of the developing solution, as well as the quality of the resulting image, pH adjusting agents such as acids and bases, buffers, preservatives, whitening agents, surfactants or the like can be optionally incorporated in the physical developing solution so according to the conventional methods.

Of these additives, ammonium aqueous solution or sodium hydroxide aqueous solution is particularly preferably used in order to raise pH.

The physical development may be carried out in a 65° - 90°C high temperature nickel plating bath using a sodium hypophosphite reducing agent or the same bath under high-speed plating conditions. The resulting image can also be treated for about 5 minutes with, for example, a 5% aqueous solution of hydrochloric acid or nitric acid to selectively remove a portion of the transparent resin of the light transmissive portions.

In addition to the system consisting of the transparent resin, the development restrainer and the metal complex compound or metal compound, the photosensitive materials which can be used in the present invention are (a) silver salt materials represented by silver halides and organic silver salt usual as Dry Silver (registered trade mark). (b) a binary system of a diazonium salt and a coupler, (c) diazo materials (registered trade mark), and PD Process materials (registered trade mark), (10 represented by Kalvar Film (registered trade mark) and PD Process materials (registered trade mark), (10 photopolymentezation crossitiving-type photopolymer materials represented by acrylic monomers and polyvinyl cinnamic acid, (e)electrophotographic photoreoptors or its transfer products such as CAS, ZnO and polyvinyl carbazole which form a toner image, (f) electrophotographic materials such as thermoplastic electrophotographic photoreoptors which form a frost image, (f) a binary system of a leuco dye and control terrational control terration control terration control terration control terration control terration control terration control ter

motybdenum-tungsten compounds which form an image of pigments or dyestuffs.

In the some cases of the photosensitive materials described above, the exposed portions exhibit light not be comediated to the composed portions exhibit light transmission properties. In the some cases, screening properties and the unexposed portions exhibit light transmission p

Ultravlolet rays, visible rays, Infrared rays, X-rays, electron beams and the like can be used as a light irradiated to such photosensitive material.

Although CCD is commercially available and easy to obtain, it cannot read a diazo image (visual recognition is possible) because of its infrared ray transmissive property which results from that the range of wavelength sensitivity of CCD is within the infrared area. In contrast, a non-silver photosensitive material can read the image.

o Also, CCD can read an ordinary photofilm using silver; however, any material using silver must be usually handled only in a dark room. On the other hand, a non-silver photosensitive material is advantageous because it can be handled even in a light room and has a high resolving power.

Another advantage of a non-silver photosensitive material is that a solvent type photosensitive material layer composition can be used, depending upon its components used, resulting in easy drying after coating. 35 The non-silver photosensitive material has all advantages abovementioned.

A reflective metallic thin film layer 6 is then formed on the thus formed recording layer 5 consisting of the light transmissive portions 3 and light screening portions 4.

The reflective metallic thin film tayer is formed using metals which form pits during heating such as Cr. Ti, Fe, Co, Ni, Cu, Ag, Au, Ge, Al, Mg, Sb, Te, Pb, Pd, Cd, Bi, Sn, Se, In, Ga and Rb, alone or in 40 combination of two or more metals. When the reflective metallic thin film layer 6 is used as a second recording layer to further write information therein by irradiation of an energy beam, it is preferable to use low melting metals such as Te, Zn, Pb, Cd, Bi, Sn, Se, In, Ga, and/or Rb as a main component. Alloys such as Te-Se, Te-Se-Pb, Te-Pb, Te-Sn-S, Sn-Cu, Te-Cu, and Te-Cu-Pb are particularly preferred.

Of these alloys, a Te-Cu alloy containing from 5 to 40 atomic percent of Cu, and a Te-Cu-Pb alloy containing from 5 to 40 atomic percent of Cu of Pb are particularly preferred when the wavelength of an Irradiation energy beam for readout is set at 650 nanometers or ligher. When the reflective metallic thin film layer made of these alloys is used as the second recording layer, recording pits exhibiting little turbulence at the periphery are obtained. Further, when the wavelength of the irradiation energy beam for readout is at least 650 nanometers, particularly from 700 to 900 nanometers, the ratio of the reflectivity of pits which are recording portions to that of metallic thin films which are unrecording portions, i.e., relative reflectivity is small. Thus, a reflective metallic thin film having excellent information readout characteristics is obtained.

When Sn-Cu alloys containing from 1 to 40 atomic percent of Cu are used, a reflective metallic thin film exhibiting little turbulence of the peripheral portion of recording pits and low toxicity is obtained.

When the reflective metallic thin film layer 6 is simply used as a reflective layer without writing any information, it is preferable that the reflective metallic thin film layer be formed from metals or alloys having particularly excellent light reflection such as Al, Cr, Ni, Ag and Au.

In order to form such a reflective metallic thin film layer on the recording layer, the metal or alloy as described above is provided and may be applied onto the recording layer by the previously known processes such as sputienting, vacuum deposition, ion plating and electroplating to form a thin film therene. It is preferable that the film thickness of the reflective metallic thin layer be from 20 to 1000 nm, preferably 100 - 500 nm. Optionally, a mutilitary film composed of the metal described above, such as a mutilitaryer film of an in film and a To film can be used as the reflective metallic thin film. Thin films composed of composite materials of the above metal and an opragic compound or inorganic compound, for example, thin films such as To-Cita, To-Cis, Te-styrene, Sn-SO<sub>2</sub>, Ga-Sn and SnS-S, and multilayer films such as Sig-City/SiO<sub>2</sub>/A can be used as the reflective metallic thin film.

Further reflective metallic thin films which can be used in the present invention are a thin film wherein in effectivity is imparted by cohesing dystuffs such as cyanine; a thin film wherein dysetuffs or metal particles such as silver are dispersed in themroplastic resins such as nitrocellulose, polystyrene and polystylene; a thin film wherein dystuffs or metal particles are achieved to the surface of such thermoclastic resins, and the like.

The reflective metallic thin films can be composed of further compounds wherein phase transition occurs by irradiation of an energy beam to vary its reflectivity, such as Te oxide, Sb oxide, Mo oxide, Ge oxide, To oxide-Te, and Te-Sh.

Chalcogens, color formation-type MoO<sub>2</sub>-Cu and MoO<sub>2</sub>-Sn-Cu can be used as the material for the reflective metallic thin film, and optionally multilayer products of a foam formation-type organic thin film and a an entallic thin film can be also used as the reflective metallic thin film.

a metallic unit titler cart of also used as the reflective information in the first further, optomagnetic recording materials such as GdCo, TbCo, GdFe, DyFe, GdTbFe, GdFeBi, TbDvFe and MnCuBi can be used as the material for the reflective metallic thin film.

The reflective metailic thin films of various types as described above can be used in combination.

The reflective metallic thin film layer can be provided on the recording layer together with a separate substrate on which said thin film layer is provided, instead of providing directly on the recording layer.

Writing of information in the reflective metallic thin film layer as described above and readout of information written in the optical Information carrier according to the present invention will now be described.

Writing of information in the reflective metallic thin film layer is carried out by focusing an energy beam so such as a laser beam having a wavelength of from 300 to 1100 nanometers by means of a lens or the like onto the metallic thin film layer to irradiate it with the energy beam, and vaporizing or segregating the metal of the irradiated portions to form spots, for example pits.

Alternatively, said writing is carried out by forming a spot by color change or phase change of said reflective thin film layer. Preferably, the intensity of the energy beam is from 0.1 to 100 mW, the pulse width is 5 naneseconds to 500 milliseconds, and the diameter of the beam is from 0.1 to 100 micrometers.

Laser beam such as a semiconductor beam, an argon laser, a helium-neon laser, infrared flash and the like can be used as the energy beam irradiated onto the reflective metallic thin film layer.

On the other hand, readout of information written in the optical information carrier according to the present invention is carried out by focusing an energy beam, a white light or a tungsten light having such a few energy level that it does not melt the reflective metallic thin film layer, onto the (first) recording layer consisting of the light transmissive portions and the light screening portions and/or metallic thin film layer acting as the (second) recording layer according to the necessity, having recording pits a sensor the life from the recording layer-free side of the substrate to irradiate them with the energy beam or the light, and detecting the intensity of a reflected light in connection with the phase shift.

As described above, when the non-silver photosensitive material is used, at the light screening portions of the recording layer, metal deposits in the vicinity of the metal developing nuclei as a center to form a tone similar to a black. Accordingly, when the light screening portions are irradiated with an irradiation beam for readout, the irradiation beam is absorbed at such portions to decrease the reflectivity. On the other hand, at the light transmissive portions, the irradiation beam is not very absorbed and reaches the reflective metalic thin film layer. Accordingly, the reflectivity at the light transmissive portions is a large value.

The metallic thin film layer corresponding to the unrecording portions of the reflective metallic thin film layer, when it acts as the second recording layer, exhibits high reflectivity, whereas the pit portions corresponding to the recording portions exhibit low reflectivity.

Thus, information written in the optical information carrier according to the present invention can be so read out by reading out the difference in reflectivity between the light screening portions and light transmissive portions of the first recording layer, and/or the difference in reflectivity between the pit portions and unrecording portions of the second recording layer.

In addition to cards such as a credit card and a bank card, the optical information carrier according to the present invention can be employed in uses such as a license, medical control records such as a clinical chart, a passport, a dictionary for a word processor, a check for travel, and a soft package for a computer.

Because the optical information carrier according to the present invention has the first recording layer consisting of the photosensitive material layer, and the second recording layer consisting of the reflective thin film layer, it has the following effects or advantages.

(a) It is possible to carry out far higher density recording as compared with the magnetic recording material, and it is significantly difficult to alter the written information.

(b) When writing of information in the reflective thin film layer is carried out, said information written therein can be readout on the basis of the difference in light reflectivity.

therein can be readout on the basis of the difference in light reflectivity.

(c) Writing of information in the recording layer can be carried out by mass productive processes such

as Imagewise exposure without using any laser beam.

(d) When the system consisting of the transparent resin, the development restrainer and the metal complex compound or metal compound is used as the photosensitive material, the operation can be carried out in a light room.

The present invention also provides an optical card having such an optical recording material.

An optical card according to the present invention comprises an optical information carrier provided on a card substrate, the optical information carrier comprising (a) a substrate for an optical information carrier, (b) a recording layer provided at the lower surface of the substrate for the optical information carrier, the secording layer consisting of light transmissive portions and light screening portions, and (c) a reflective thin limit layer provided at the lower surface of the recording layer, wherein the optical information carrier is provided on the card substrate so that the thin film layer comes into contact with the card substrate.

In the optical information carrier secured to the optical card, information has been already written in the recording layer thereof. In order to further write information in the thin film layer, the thin film layer may be as irradiated with an energy beam in the, form of spots. Readout of the information written in the recording layer and/or thin film layer is carried out by irradiating the optical card with a record playback [light from the side of the substrate for the optical information carrier and detecting the intensity of a reflected light in connection with the obase shift.

Optical cards according to the present invention will now be described by embodiments shown in the archarings wherein a portion of members is enlarged for the convenience of description. Reference numerals of members common to Figure 1 are represented by the same reference numbers as those of Figure 1, in

Figure 2 is a sectional view of an optical card according to the present invention. The optical card 7 comprises an optical information carrier 1 provided on a card substrate 8. This optical information carrier 1 so comprises (a) a substrate 2 for the optical information carrier, (b) a recording layer 5 provided at the lower surface of the substrate, the recording layer consisting of light transmissive portions 3 of light screening portions 4, and (c) a reflective metallic thin film layer 6 provided at the lower surface of the recording layer 5. The optical information carrier is provided on the eard substrate 8 obtains thin film layer 6 comes into contact with the card substrate 8. Optionally, a magnetic recording layer 8 may be provided on the surface of the optical card 7. In necessary, IC memory, photographs, engraved images, letters, marks, relief letters referred to as imprint or the like may be provided on the surface of the optical card. Thus, it is possible to cope with various playback systems by one card, and forgery can be more effectively prevented.

Figure 3 is a sectional view of another embodiment of an optical card 7. The optical card 7' shown in Figure 3 comprises a recording layer 5 and a metallic thin film layer 6 provided on a portion of the surface of a su

Any material which can be used as a conventional card substrate can be used as the card substrate 8. Specific examples of the materials from which the card substrate is produced are polyvinyl chloride, vinyl chloride/Mnyl acetate copolymer, polyvinylidene chloride, acrylic polymers such as polymethyl se mettacrylate, polystryene, polyvinyl butyral, acetylcellulose, styrener/utadiene copolymer, polythylene, polytropylene, polycarbonate, and the like. Optionally, sheets of metals such as iron, stainless steel, aluminum, tin, copper, and zinc, synthetic papers, papers and the like can be used. The laminates of the materials as described above can be used. The optical information carrier for use herein is as described above in detail.

An optical card according to the present invention is produced as follows:

First, as described above, a recording layer and a metallic thin film layer are provided on a substrate for an optical information carrier to form an optical information carrier. When the substrate for the optical information carrier is incorporated in an optical card, it also acts as a card protective layer.

The card substrate and the substrate for the optical information carrier are then laminated via an adhesive layer such as a hot-heat datesive or a thermosetting adhesive so that the metallic thin film layer of the optical information carrier comes into contact with the card substrate. The laminate is then pressed by a heated roll at about 90 - 150 °C or the like to produce an optical card.

5 Optionally, an optical card can also be produced as follows: a recording layer containing a hydrophilic resin as a binder and a reflective metallic thin film layer are provided on a substrate tor an optical information carrier. A protective film of arrylic resins or the like is applied to the reflective metallic thin film layer by a screen printing process or the like to impart waterproof properties to such portions. In this case, the protective film is not provided at the periphery of the substrate for the optical recording material. This optical Information carrier is then immersed in warm water to remove the hydrophilic resin present at the protective layer-free portions, and thereafter dried.

On the other hand, a concave for embedding the recording layer and metallic thin film layer of the optical recording material is formed in the card substrate such as white polyvinyl chloride films by a hot pressing process or the like, and an adhesive layer is affixed to the surface of the card substrate.

5 The optical information carrier and the card substrate are then taminated so that the metallic thin film layer of the optical information carrier comes into contact with the card substrate, and pressed by means of a heated roll or the like to produce an optical card.

An optical card of the present invention can also be produced by providing on a card substrate an optical information carner and a card protective layer in this order.

an optical card 11 shown in Figure 4 comprises a card substrate 8, an optical recording material 1 ambedded in the card substrate 8 and a card protective layer 10 provided on these members. This optical information carrier comprises (a) a substrate 2 for an optical information carrier, (b) a recording layer 5 provided at the lower surface of the substrate, the recording layer consisting of light transmissive portions 3 and light screening portions 4, and (c) a reflective metallic thin film layer 6 provided at the lower surface of as the recording layer 5. The optical information carrier is provided on the card substrate 8 so that the metallic thin film layer 6 comes into contact with the card substrate 8.

Optionally, a magnetic recording layer 9 may be provided on the surface of the optical card 11. IC memory, photographs, engraved images, letters, marks, relief letters referred to as imprint, or the like may also be provided on the surface of the optical card.

Any materials which can be used as a conventional protective layer (overcoat) can be used as the card protective layer 10 so long as they have light transmission properties. Specific examples of the materials which can be used in the present invention are films of resins such as polyvinyl chloride, polyethylene terephthalate, polyethylene, polypropylene, polystyrene, and polycarbonate.

Such an optical card can be produced as follows:

First, a concave for embedding an optical information carrier is formed in a card substrate such as polyethylene terephthelate and white rigid polyethyl chloride by a hot pressing process or the like. If necessary, the card substrate surface including the concave is subjected to primer treatment for adhesion.

The thus formed optical information carrier is embedded in the concave of the card substrate, and a transparent polycarbonate film having, for example, a hot-melt adhesive layer at one surface thereof is superposed thereon. The laminate is pressed by means of a hot-fixing roll heated to from about 90° to 150°C to produce an optical card.

Optionally, an optical card can be produced by previously affixing the thus formed optical information carrier to a card protective layer such as transparent polyvinyl chloride via an adhesive layer; susepposing the resulting laminate on the card substrate having a concave previously formed by a hot pressing process 45 or the like, via an adhesive layer so that the optical Information carrier is embedded in the concave; and then pression the laminate by means of a header oil.

Another examples of the optical card of the present invention will be illustrated with reference to an embodiment shown in Floure 5.

An optical card 31 of the present Invention comprises, as can be seen from the section of Figure 5, a ocard substrate 32 and an optical recording part 33, both being interposed by an adhesive layer and being bonded into an integral body.

The optical recording part 33 is formed of a laminate comprising: an optical recording substrate 35; a council layer 36 being provided on the upper surface of the substrate 35; a recording layer 39 provided on the lower surface of the substrate 35; the layer 39 consisting of light transmissive opridies 37 and light screening portions; and a reflective metallic thin film layer 40. Information can be written in the metallic thin film layer so as to work as a second recording layer by using low melting point metals such as Te, Zn, Pb and the like for the metallic thin film layer.

On the other hand, the substrate 32 is formed of a laminate consisting of an opaque material layer 322, and a transparent material layer 328. While rigid polyvinir, toloride is preferably used as the opaque material layer 32a and transparent rigid polyvinyl chloride is preferably used as the transparent material layer 32a.

In some cases, a magnetic recording layer 41 may be provided in the transparent material layer 32b. A first recording layer 39 and the metallic thin layer 40 may be provided on a partial surface of the optical recording substrate 35 instead of the entire surface thereof. Further, according to necessity, such things may be additionally provided on the surface or the back of the optical card as IC memories, photographs, soulptured images, characters, marks, relief characters so called imprint and the life.

In an optical card 31 of another embodiment shown in Figure 6, a barrier layer 42 is provided between a recording layer 39 and a metallic thin film layer 40 of an optical recording portion 33. Other construction is the same as the optical card of Figure 5. This barrier layer 42 is provided in order to prevent the deterioration of the metallic thin film layer 40 due to temperature change. This barrier layer is a proposocy material.

A cured surface layer 36 is to increase the surface hardness of the optical card 31 at the side of optical executing portion to protect the same thereby preventing the card from being scratched during bearing or usage thereof. Thus, the card can be improved in durability and in confidence of accuracy of writing and reading.

Examples of the cured surface layer are any type of curing agents such as silicones, acrylates, or molamines, urethanes, epoxides; metallic oxide such as Al<sub>2</sub>O<sub>3</sub>, SiO<sub>2</sub> and the like; or plasma polymerized membrane and the like.

A barrier layer 42 is provided so that the photosensitive material forming the first recording layer 39 may not have physical and chemical adverse effect on the second recording layer or metallic thin layer 40. Particularly when the photosensitive material of the first recording layer is hygroscopic, the barrier layer 26 iseffective to prevent the second recording layer from deterioration at an elevated temperature or an elevated moisture.

Examples of the material for barrier layer are acrylates, melamines, urethanes, celluloses, polyethylene, polymynyl chloride, polyvinylldene chloride, metallic oxides such as Al<sub>2</sub>O<sub>3</sub>, SiO<sub>2</sub> and the like, and plasma polymerized membrane.

As an adhesive forming an adhesive layer 34, a variety of adhesives can be employed as exampled by hermosetting adhesives such as polyurethanes, epoxides and the like, or heat sensitive adhesive such as acrylate restins, polyvinyl acetate resins, polyethylenevinyl acetate copolymers and the like. For the application requiring chemicals resistance, thermosetting adhesives, preferably urethanes adhesives are used.

The present invention also relates to an optical card wherein data readout is optically carried out by a line sensor.

Recently, cards using a magnetic medium have been widespread. In order to carry out higher density data recording, cards containing IC memory and optical data recording cards have been developed.

A large amount of data are recorded in the optical data recording cards, and it is suitable to use a line sensor to rapidly read out. That is, the line sensor can monitor elongated regions to read out the data in the recion and can simultaneously read out one row of data.

It is necessary that the situation and pose relations between the data recording regions of the card and the line sensor be accurately conformed. If the predetermined relations are not ensured, then readout cannot be carried out.

The present invention provides an optical data recording card having means capable of accurately conforming the situation and pose relation against the line sensor.

In order to achieve this object, a predetermined portion of a data recording region is provided with bars disposed in a direction coinciding with a data readout direction or a fine sensor, and these bars are detected by means of the line sensor to accurately maintain the situation and pose relations between a card and the line sensor.

Embodiments of the present invention will be described with reference to Figures 7, 8 and 9.

Figure 9 is a plan view of an optical data recording card according to the present invention. A card 100 made of plastics or the like is provided with a printing region 15 of letters and patterns and an optical data recording region 20.

Figure 7 is a view of a further embodiment of the present invention, and shows an enlarged optical data recoording region 20 shown in Figure 9. Longliudhally extending bars 21A and 21B having a length approximately equal to the longitudinal length of a laterally elongated rectangular region are provided three by three at both the left side and the right side of the laterally elongated rectangular region. A lateral bar

22A is provided in order to connect an upper end of the bar 21A with an upper end of the bar 21B and a lateral bar 22B is provided in order to connect a lower end of the bar 21A with a lower end of the bar 21B. The data are recorded at the region surrounded by these longitudinal bars 21A and 21B and lateral bars 22A and 22B.

The data are read out by means of a line sensor 30. The line sensor 30 performs data readout in a direction shown by an arrow. If the card is set against the line sensor so that the arrow overlaps the longitudinal bars 21A and 21B, then the card and the line sensor exhibit an accurate situation relation and an accurate pose relation. In this case, if the line sensor moves laterally parallel, then data can be accurately read out.

Figure 8 is a view of a still further embodiment of the present invention. Longitudinab bars 21A\* and 21B are disposed at only the portions extending from lateral bars 22A and 22B. Secause the longitudinal bars are provided in order to examine whether they coincide with the data readout direction of the line sensor or not, the presence of two portions of each longitudinal bars is satisfactory. If such two portions are spaced apart from each other as far as possible, good precision can be obtained. The longitudinal bars 21A\* and 21B are provided at the portions corresponding to both the ends of the embodiment of the longitudinal bars 21A and 21B shown in Figure 5.

While the longitudinal bars are provided at the sides of the lateral bars by three by three (3 pairs) in the embodiment described above, the longitudinal bars may be provided at the sides of the lateral bars one by one (one pair). If the set situation of the card is predetermined, the pose may be controlled by only songitudinal bars disposed at either the right or left side of the card, and the other longitudinal bars may simply exhibit the data recording region. While each of the lateral bars 22A and 22B is one bar having a relatively wide width, the lateral bars show the upper and lower lines of the data recording regions and therefore the form of the lateral bars are not limited to the embodiments illustrated.

As described above, the longitudinal bars for examining the situation and pose relations between the card and the line sensor are provided at the predetermined portion of the optical data recording region, and therefore accurate data readout is ensured by detecting the longitudinal bars by means of the line sensor. Thus, the present invention improve the convenience in using the optical data recording card.

While the present invention is illustrated by the following examples, the present invention is not limited thereto.

## Example 1

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A coating solution for forming a photosensitive material layer comprising the following ingredients was prepared. This coating solution was applied onto a previsouly undercoated polyester film having a film thickness of 188 micrometers (Lumiror C+2 available from Toray, Japan) by a Mayer ber 456 while maintaining at 183°C, and then cooled to a temperature of 5°C. The treated film was then dried at a temperature of 30°C, and film-hardening treatment was carried out for 12 hours at a temperature of 40°C to form a photosensitive material layer on the substrate. The coating weight of the coating solution for forming the photosensitive material layer was 4 grams per square meter on a dry basis.

# Composition of a Coating Solution for Forming a Photosensitive Material Layer

	Gelatin (P-2151 available from Nitta Gelatin, Japan); 8% aqueous	25.0 grams
45	solution HCl acidic aqueous solution of PdCl <sub>2</sub> (Red Sumer, ten-fold solution	14.0 grams
	available from Nippon Kanlzen, Japan) 4-Moroholino-2.5-dibutoxybenzene-diazonium borofluoride	3.0 grams
50	(DH300BFu available from Daito Kagaku, Japan); 2% DMF solution Condensation product of p-diazo-diphenylamine borofluoride and	0.7 gram
	paraformaldehyde; 5% DMF solution N,N'-Dimethylolurea; 5% aqueous solution	0.5 gram

The photosensitive material layer thus formed was then brought into intimate contact with the mask surface of a photomask wherein lines having a width of 5 micrometers were negatively patterned in the form of stripes having a pitch of 10 micrometers. The whole was exposed for 80 seconds to an ultra-high mercury vapor lamp (3 kW; distance of one meter) from the photomask side. The exposure amount was 50

mi/cm<sup>2</sup> at a wavelength of 365 nanometers.

The thus imagewise exposed photosensitive material layer was then immersed in treating solutions (A) and (B) having the following compositions in this order for 40 seconds and 100 seconds, respectively. (The treatment temperature was 25 °C.)

(A) Siba Nickel (manufactured by O	kuno Seiyaku, Japan)
Boron-type reducing agent	0.5 gram
Nickel suifate	3.0 grams
Sodium citrate	1.0 gram
Water	95.5 grams

(B) 1:1 Mixture of TMP Chemical Nickel A and TMP Chemical Nickel B		
Nickel sulfate Sodium hypophosphite NH <sub>3</sub> Aqueous solution (28%) Sodium citrate Water	9.0 grams 7.0 grams 6.5 grams 10.0 grams 67.5 grams	

Thereafter, the whole was washed with water and dried to obtain a first recording layer having light transmissive portions and black positive patterns corresponding light screening portions.

A Te-Cu-Pb alloy (at an atomic percent ratio of 80:15:5) was then subjected to sputtering for 90 seconds as a sputter target onto the first recording layer thus formed on the substrate under an argon gas pressure of 5x10-2 torr and a placing pressure of 400 V to deposit a Te-Cu-Pb metallic thin film layer having a film thickness of 30 nm, thereby forming a second recording layer.

The thus obtained optical recording material was then irradiated with a laser beam having a wavelength 30 of 790 nanometers oscillated from a laser diode from the recording layer-free side above under the following conditions: the black positive patterns already formed on the first recording layer was used as a guide (tracking); the laser feam was focused on the surface of the Te-Cu-Pb metallic thin film layer under a power of 5 mW at a beam diameter of 2 micrometers; and the pulse width was one nanosecond. Circular recording pits having a diameter of 2 micrometers were formed in the metallic thin film layer.

### Example 2

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A coating solution for forming a photosensitive material layer comprising the following ingredients was prepared. This coating solution was applied to a previously corona-treated triacetate film having a film 40 thickness of 18 micrometers (Fujitack available from Fuji Shashin, Japan) by means of a Mayer bar #36 while warming to 35°C, and then cooled to a temperature of 5°C. The whole was then dried at a temperature of 30 °C and a film-hardening reaction was carried out for 3 hours at a temperature of 40 °C. The dry weight of the resulting photosensitive material layer was 3.6 grams per square meter.

### Composition of a Coating Solution for Forming a Photosensitive Material Layer

Gelatin (#150 available from Nitta Gelatin, Japan); 7% aqueous	28.6 grams
solution HCl acidic aqueous solution of complex of PdCl <sub>2</sub> and EDTA (1000	14.0 grams
ppm on a PdCl <sub>2</sub> basis; pH = 2.8) 4-Morpholino-2,5-dibutoxybenzene-diazonium borofluoride (DH 300	3.0 grams
BFu available from Daito Kagaku, Japan); 2% DMF solution Diazoresin (D-011 available from Sinko Giken, Japan); 5% aqueous solution	0.7 gram
solution N,N'-Dimethylolurea; 5% aqueous solution NN HCI	2.0 grams 2.5 grams

The photosensitive material layer thus obtained was imagewise exposed in the same manner as described in Example 1, and then immersed in the treating solutions (A) and (B) (20 °C) in this order for 30 seconds and 90 seconds, respectively to obtain a first recording layer having light transmissive portions and black positive patterns corresponding to light screening portions.

Te was then deposited on the first recording layer thus formed on the substrate to a film thickness of 25 nm to form a second recording layer.

The thus obtained optical recording material was then irradiated with a He-Ne laser beam having a wavelength of 632.8 nanometers from the recording layer-free side under the following conditions: the black positive patterns already formed on the first recording layer was used as a guide (fracking), the laser beam as was forcused on the surface of the Te metallic thin film layer under a power of 5 mW at a beam diameter of 3 micrometers; and the pulse width was 150 nanometers. Circular recording pits having a diameter of 3 micrometers were formed in the metallic thin film layer.

Recording pits of the recording material having written information were then photographed from the recording layer-free side of the substrate via a microscope by means of a CCD camera (TM1300 available from Tostiba, Japan). When it was converted into an electrical signal, an input signal during recording was confirmed.

# Example 3

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An aqueous solution comprising the following ingredients was applied to a previously corona-treated polyester film (Lumiror T100 available from Toray, Japan; 100 microns thick) to a dry weight of 4.0 grams. The whole was dried and film-handening treatment was carried out for 12 hours at a temperature of 40 °C.

# Composition of a Coating Solution

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Gelatin (P-2151 available from Nitta Gelatin, Japan); 30% aqueous solution Glutaric acid: 10% aqueous solution	10 grams	l
Glutaric acid: 10% aqueous solution	1.2 grams	ı

A coating solution for forming a photosensitive material layer comprising the following ingredients was then prepared, and applied to the surface of the gelatin layer of the above film by means of a Mayer bar #12. The whole was dried for 10 minutes at a temperature of 70 °C to prepare a photosensitive material layer.

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### Composition of a Coating Solution for Forming a Photosensitive Material Layer

HCl acidic aqueous solution of PdCl₂ (Red Sumer,	10 grams	
ten-fold solution available from Nippon Kanizen, Japan)		
Diazoresin (D-011 available from Sinko Giken, Japan)	0.6 gram	
Surfactant (Elmabon T-40 available from Tohho Kagaku,	0.1 gram	
Japan)		
Water	60 grams	

The thus obtained photosensitive material layer was imagewise exposed in the same manner as described in Example 1, and immersed in solutions (A) and (B) at 25°C in this order for 30 seconds and 60 seconds, respectively to obtain a first recording layer having light transmissive portions and black positive patterns corresponding to fillnt screening portions.

Thereafter, an optical recording material was prepared in the same manner as described in Example 1.

### Example 4

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An optical recording material was prepared in the same manner as described in Example 2 except that diazorasin was replaced with a 5% DMF solution of the condensation product of p-diazodiphenylamine borofluoride and paraformatiohyde.

### Example 5

An optical recording material was prepared in the same manner as described in Example 1 except that the substrate and the photosensitive material layer provided thereon were replaced with a Minicopytish Film HR II manufactured by Fuji Shashin Film K.K., Japan. The Minicopytish Film HR II comprises a polyethylene terephthalate film as a substrate, and a silver halide emulsion layer formed thereon.

#### Example 6

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An optical recording material was prepared in the same manner as described in Example 1 except that the substrate and the photosensitive material layer provided thereon were replaced with a Fuji Diazo Film 35 M-4208-P7 manufactured by Fuji Shashin Film K.K., Japan. The Fuji Diazo Film M-4208-P7 comprises a poblyethylene terephthalate film as a substrate, and a coating of a binary system of a diazonium sait and a coupler provided on the substrate.

### Example 7

A coating solution forming a photosensitive material layer comprising the following ingredients was prepared. This coating solution was applied to a polyester film having a film thickness of 188 micrometers (Lumimor #100 available from Toray, Japan) by means of a wire bar #36, and dried in an oven at 80 °C to form a photosensitive material layer having a film thickness of 4 micrometers.

### Composition of a Coating Solution for Forming a Photosensitive Material Layer

Acrylic acid/vinyl acetate copolymer resin (Corponiel Pc-50M(H) available	20 grams
from Nippon Gosei Kagaku Kogyo, Japan); 20% ethanolic solution	
4-Morpholino-2,5-dibutoxybenzene-diazonium borofluoride (No.11 BFu	3.0 grams
available from Recipe Chemical); 10% MEK solution	ľ
PdCl <sub>2</sub> solution (PdCl <sub>2</sub> :concentrated hydrochloric acid :ethanol = 0.1:5:100)	10 grams
Polyethylene oxide (PEO-3 available from Seitetsu Kagaku, Japan); 1%	2.0 grams
ethanolic solution	-
p-Toluenesulfonic acid; 5% ethanolic solution	1.0 gram

The photosensitive material layer thus formed was then brought into intimate contact with the mask surface of a photomask wherein lines having a width of 5 micrometers were negatively patterned in the form of stripes having a pitch of 10 micrometers. The whole was exposed for 60 seconds to an ultra-high mercury vapor lamp (3 kW, distance of one meter) from the side of the photomask. The exposure amount s was 50 micro? at a weekendth of 355 naometers.

The thus imagewise exposed photosensitive material layer was then immersed in the treating solutions (A) and (B) described in Example 1 in this order for 49 seconds and 100 seconds, respectively. (The treatment temperature was 25 °C.)

Thereafter, the whole was washed with water and dried to obtain a recording layer having light transmissive portions and black positive patterns corresponding to light screening portions.

The photomask patterns used herein were those wherein data comprising laid out addresses and guidelines were represented in dot array of circles having a diameter of 5 micrometers.

All was deposited on the thus patterned recording layer to a film thickness of 150 nm to form a reflective metallic thin-film layer. Thus, an optical recording material was obtained.

When the optical recording material was irradiated with a beam of laser diode (790 nm) from the substrate side to read out a reflected light of the circle dot array using the black layer corresponding to the light screening portions of the recording layer as a guide line, it was confirmed to be identical with data inout signal of the mask original plate.

#### 20 Example 8

A coating solution for forming a photosensitive material layers comprising the following ingredients was prepared. This coating solution was applied to a previously corona-treated triscated film having a lim thickness of 100 micrometers (Fuljitack available from Fulj Shashin Film, Japan) by means of a Mayer bar 3/86 while warming to 35°C, and then cooled to a temperature of 5°C. The whole was then dried at a temperature of 30°C and a film-hardening reaction was carried out for 3 hours at a temperature of 40°C. The dry weight of the resulting photosensitive material layer was 3.8 grams per square meter.

### Composition of a Coating Solution for Forming a Photosensitive Material Layer

	0.14 4940 914 4 194 0.14 1 1 1-4	1
	Gelatin (#150 available from Nitta Gelatin, Japan); 7% aqueous solution	28.6 grams
35	HCl acidic aqueous solution of a complex of PdCl₂ and EDTA (1000 ppm on a PdCl₂ basis; pH = 2.8)	14.0 grams
	4-Morpholino-2,5-dibutoxybenzene-diazonium borofluoride (DH 300 BFu available from Daito Kagaku, Japan); 2% DMF solution	3.0 grams
	Diazoresin (D-011 available from Sinko Giken, Japan); 5% aqueous solution	0.7 gram
40	N,N-Dimethylolurea; 5% aqueous solution	2.0 grams
	1N HCI	2.5 grams

The photosensitive material layer thus obtained was imagewise exposed in the same manner as 4d described in Example 7, and then immersed in the treating solutions (A) and (B) (20°C) in this order for 30 seconds and 90 seconds, respectively to form a recording layer having light transmissive portions and black positive patterns corresponding to light screening portions.

Al was then deposited on the recording layer thus formed on the substrate to a film thickness of 300 nm to form a reflective recording layer. Thus, an optical information carrier was obtained.

#### Example 9

An optical information carrier was prepared in the same manner as described in Example 8 except that diazoresin was replaced with a 5% DMF solution of the condensation product of p-diazodiphenylamine so borofluoride and paraformaldehyde.

### Example 10

An optical information carrier was prepared in the same manner as described in Example 7 except that the substrate and the photosensitive material layer provided thereon were replaced with a Minicopyfish Film HR II manufactured by Fuji Shashin Film K.K., Japan. The Minicopyfish Film HR II comprises a polyethylene terephthalate film as a substrate, and a silver haide emulsion layer formed thereon.

### Example 11

An optical Information carrier was prepared in the same manner as described in Example 7 except that the substrate and the photosensitive material layer provided thereon were replaced with a Fuji Diazo Filin M-4208-P7 manufactured by Fuji Shashin Filin K.K., Japan. The Fuji Diazo Filin M-4208-P7 comprises a polyethylene terephthalate film as a substrate, and a coating of a binary system of a diazonium salt and a coulor provided on the substrate.

### Example 12

First, an optical information carrier used in forming an optical card was prepared as follows:

A coating solution for forming a diazo photosensitive material layer comprising the following ingredients was applied onto a previously undercoated transparent polyvinyl chloride film having a film thickness of 400 micrometers by means of a Mayer bar #36, and then dried. The coating weight of the coating solution for forming the photosensitive material layer was 1.5 grams per square meter on a dry basis.

### Composition of a Coating Solution for Forming a Photosensitive Material Layer

4-Morpholinobenzenediazonium borofluoride	25 grams
α,β-bis(m-hydroxyphenoxy)ethane	32 grams
5-Sulfosalicytic acid	20 grams
Citric acid	5 grams
Formic acid	200 milliliters
Methyl cellosolve	600 millifiters
Methyl cellosolve acetate	100 milliliters

The photosensitive material layer thus formed was then brought into intimate contact with the mask surface of a photomask wherein lines having a width of 5 micrometers were negatively patterned in the form of stripes having a pitch of 10 micrometers. The whole was exposed for 60 seconds to an ultra-high arroury vapor lamp (3 kW; distance of one meter) from the photomask side. After exposure, it was developed with an ammonla cas.

A Te-Cu-Pb alloy (at an atomic percent ratio of 80:17:3) was then subjected to sputtering for 90 seconds as a sputter target onto the first recording layer thus formed on the substrate under an argon gas pressure of 5x:10<sup>-2</sup> torr and a placing pressure of 400°V to deposit a Te-Cu-Pb metallic thin film layer having a film thickness of 30 nm thereby forming a second recording layer. Thus, an optical information carrier was second.

On the other hand, a desired printing composition was applied to the front surface of a white rigid polyvinyl chloride film having a thickness of 300 micrometers as a card substrate, and magnetic stripes were provided on the back surface thereof by a transfer process.

The card substrate and the optical information carrier were laminated via a hot-molt adhesive layer so (intyl chloride-vinyl) acetate-maleic aid reships to that the second recording layer of the optical recording material came into contact with the surface of the card substrate. The laminate was pressed by a heated roll at 120°C to produce an optical card.

### Example 13

An optical information carrier used in forming an optical card was prepared in the same manner as described in Example 7 except that a photosensitive material layer was formed as follows:

A coating composition for forming a photosensitive material layer comprising the following ingredients maintained at 35°C was applied onto a previously undercoated polycarbonate film having a film thickness of 300 micrometers by means of a Mayer bar 486, and then cooled to a temperature of 5°C. The whole was dried at a temperature of 50°C, and film-hardening treatment was carried out for 12 hours at a temperature of 40°C to form a photosensitive layer on the substrate. The costing weight of the coating solution for forming the photosensitive material layer was 4 cramps per square meter on a dry basis.

#### Composition of a Coating Solution for Forming a Photosensitive Material Laver

Gelatin (P-2151 available from Nitta Gelatin, Japan); 8% aqueous solution	25.0 grams
HCl acidic aqueous solution of PdCl <sub>2</sub> (Red Sumer, ten-fold soltuion available from Nippon Kanizen, Japan)	14.0 grams
4-Morpholino-2,5-dibutoxybenzene-diazonium borofluoride (DH 300 BFu available from Datio Kaoaku, Japan); 2% DMF solution	3.0 grams
Condensation product of p-diazodiphenylamine borofluoride and paraformaldehyde: 5% DMF solution	0.7 gram
N,N'-Dimethylolurea; 0.5 % aqueous solution	0.5 gram

This optical information carrier is one wherein no information is written in the reflective metallic thin film layer and information written in the first recording layer is read out.

Further, an acrylate resin (Daiyanal LR 90 available from Mitsubishi Rayon, Japan) was applied as a protective film onto the reflective metallic thin film layer by a screen printing process.

The optical information carrier thus obtained was then immersed in warm water, and the gelatin layer at the portions having no protective layer was removed. The material was then dried to prepare an optical information carrier provided with the first and second recording layers at only central portion rather than the entire surfaces of the substrate for the ordical recording material.

On the other hand, a white polywinyl chloride film having a thickness of 400 micrometers as a card substrate and the thus prepared optical information carrier were claimhisted via an popxy resin adhesive so that the second recording layer of the optical information carrier came into contact with the card substrate. The laminate was pressed by means of a roll or the file to produce an optical card.

### 35 Example 14

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An optical card was produced in the same manner as described in Example 13 from an optical information carrier which was obtained in the same manner as described in Example 2 except that the thickness of the triscotate film was 100 micrometers. The resulting optical card was irradiated with a He-Me of leser beam having a wavelength of 852.6 nanometers from the side of the substrate for the optical recording material under the following conditions: the black positive patterns already formed in the first recording layer was used as a guide (fracking); the leser beam was focused on the surface of the To metallic thin film layer described above under a power of 5 mW at a beam diameter of 3 micrometers; and the pulse width was 150 nanoseconds. Circular recording pits having a diameter of 3 micrometers were formed in the metallic strin film layer.

### Example 15

An optical card was produced in the same manner as described in Example 12 except that an optical information carrier embedded in the optical card was prepared in the same manner as described in Example 7.

In this example, in preparing the photosensitive material layer of the optical information carrier, a coating solution for forming the photosensitive material layer was applied to a polycarbonate film having a film thickness of 300 micrometers (manufactured by Teijin Kasei, Japan) by means of a wire bar #12 and 55 dried in an 80 °C oven to form the photosensitive material layer having a film thickness of 4 micrometers.

This optical information carrier is one wherein no information is written in the reflective metallic thin film layer and information written in the first recording layer is read out.

When the optical card having embodded the optical information carrier therein was irradiated with a beam of a laser diode (790 nm) from the side of the substrate for the optical information carrier to read out a reflected light of circular dot array using the black layer corresponding to the light screening portions of the first recording layer as a guideline, it was confirmed to be idential with a data input signal of a mask or original other.

#### Example 16

An optical information carrier was prepared and then an optical card was produced in the same manner or as described in Example 13 except that the substrate and the photosensitive material layer provided thereon were replaced with a Minicopyrish Film IHR II manufactured by Fuji Shashin Film KK, Japan. The Minicopyrish Film IHR II comprises a polyethylene terephthalate film as a substrate, and a silver halide emulsion laver formed thereon.

#### 15 Example 17

An optical information carrier was prepared and then an optical card was produced in the same manner as described in Example 13 except that the substrate and the photosensitive material layer provided thereon were replaced with a Fuji Diazo Film M-4208-P7 manufactured by Fuji Shashin Film K.K., Japan. 20 The Fuji Diazo Film M-4208-P7 comprises a polyethylene terephthalate film as a substrate, and a coaling of a binary system of a diazonium salt and a coupler provided on the substrate.

#### Example 18

An optical information carrier embedded in an optical card was prepared in the same manner as described in Example 1.

On the other hand, a white rigid polyvinyl chloride film having a thickness of 400 micrometers as a card substrate was subjected to hot pressing to form a concave for embedding the optical information carrier. One surface of a transparent polycarbonate film having a thickness of 300 micrometers as a card protective so layer was provided with a hot-melt adhesive (Pracsel H-7 available from Dalsel Kagaku Kogyo, Japan), and the other surface was treated with a silicon surface hardenina opent.

The optical information carrier was then embedded in the concave of the white rigid polyvinyl chloride card substrate, and the card protective layer was superposed on the card substrate having embedded the optical information carrier therein, via the adhesive layer. They were pressed by means of a heated roll swing a surface temperature of 120°C to laminate them.

The thus obtained optical card was then irradiated with a laser beam having a wavelength of 790 nanometers oscillated from a laser diode, from the card protective layer side under the following conditions: the black positive patterns already formed on the first recording layer was used as a guide (tracking); the laser beam was tocused on the surface of the Te-Cu-Pb metallic thin film layer under a power of 5 mW at a beam diameter of 2 micrometers; and the putse width was one nanosecond. Circular recording pits having a

diameter of 2 micrometers were formed in the metallic thin film layer.

#### Example 19

46 An optical information carrier prepared in the same manner as described in Example 18 was affixed to a white polyvinyt chloride film having a thickness of 400 micrometers as a card protective layer via a doublested achiesive tape (Double Tack Tape 555 available from Seksiuk Lagaku Kogoyo, Japan). The entire surface of the card protective layer having affixed the optical recording material thereto was provided with a viruly chloride - viruly acetate - maleic acid resin layer (Estec M available from Sekisul Kagaku Kogyo, Japan).

On the other hand, a white rigid polyvinyl chloride film having a thickness of 300 micrometers as a card substrate was subjected to hot pressing to form a concave for embedding the optical recording mateiral. The card substrate and the card protective layer having affixed the optical recording material thereto were laminated via an epoxy resin adhesive (Epikote 828, Epomate 001 available from Yuka Shell Epoxy) so that so the optical information carrier affixed to the card protective layer was embedded in the concave. The laminate was then oressed to form an optical card.

### Example 20

An optical card was produced in the same manner as described in Example 18 except that an optical information carrier embedded in an optical card was prepared in the manner as described in Example 2 and a triacetate film had a film thickness of 100 micrometers.

The optical card obtained was then irradiated with a He-Ne laser beam having a wavelength of 632.8 nanometers from the card protective layer side under the following conditions: the black positive patterns already formed on the first recording layer was used as a guide (fracking); the laser beam was forcused on the surface of the Te metallic thin film described above under a power of 5 mW at a beam diameter of 3 micrometers; and the pulse width was 150 nanoseconds. Circular recording pits having a diameter of 3 micrometers wave formed in the metallic thin film.

#### Example 21

An optical card was produced in the same manner as described in Example 18 except that an optical information carrier embedded in the optical card was prepared in the same manner as described in Example 7.

This optical information carrier is one wherein no information is written in the reflective metallic thin film layer and information written in the first recording layer is read out.

When the optical card having embedded the optical recording material therein was irradiated with a beam of a laser dided (790 nm) from the card protective layer side to read out a reflected light of circular dot array using the black layer corresponding to the light screening portions of the first recording layer as a quideline, it was confirmed to be indential with a data insut storal of a mask original plate.

### 25 Example 22

An optical information carrier was prepared and then an optical card was produced in the same manner as described in Example 18 except that the substrate and the photosensitive material layer provided thereon were replaced with a Minicopyfish Film HR II manufactured by Fuji Shashin Film K.K., Japan. The so Minicopyfish Film HR II comprises a polyethylene terephthelate film as a substrate, and a silver halide emusion layer formed thereon.

#### Example 23

is An optical information carrier was prepared and then an optical card was produced in the same manner as described in Example 18 except that the substrate and the photosensitive material layer provided thereon were replaced with a Fuji Diazo Flim M-4208-P7 menufactured by Fuji Shashin Flim K.K., Japan. The Fuji Diazo Flim M-4208-P7 comprises a polyethylene terephthalate film as a substrate, and a coating of a binary visite on of a diazonium sait and a coupler provided on the substrate.

#### Example 24

A white rigid polyvinyl chloride film having a thickness of 300 micrometers as a card substrate was subjected to hot pressing to form a concave for embedding an optical recording material.

5 The optical information carrier prepared in the same manner as described in Example 18 was embedded in the concave formed in the card substrate described above so that the second recording layer of the optical information carrier came into contact with the card substrate.

A transparent polyvinyl chloride film having a thickness of 400 micrometers as a card protective layer was then superposed thereon, and thereafter the stack was subjected to heat and pressure for 30 minutes so at a temperature of 150 °C under a pressure of 120 kg/cm² by means of a pressing machine to integrate it. Thus, an optical card was produced.

# Example 25

on a polycerbonate film having a thickness of 400 micrometers was applied gravure coating of a primer (Primer PC-4 available from Shintels Kagaku, Then, gravure coating of a silicence type surface hardening agent (K-12-2150 available from Shintels Kagaku, Japan) was applied thereon to be subjected to curing at 100 °C for one minute for obtaining a surface oured laver. On the back surface of said polycarbonate film

was applied gravure coating of photosensitive material layer forming coating solution having the following compositions. The amount of photosensitive material layer forming coating solution applied was 3 g/m² at a dried state.

6 Composition of a Coating Solution for Forming a Photosensitive Material Layer

	10% methyl ethyl ketone solution of polyvinylmethylether maleic	20 parts by weight
10	anhydride (Gantietz AN 139 available from G.A.F. Corp) 20% methyl ethyl ketone solution of poly(vinyl acetate) (Esneal C-2	20 parts by weight
	available from Sekisui Kagaku, Japan) 25% methyl cellosolve solution of acrylate type resin (L-40 available from	12 parts by weight
	Soken Kagaku, Japan) 0.1% methyl cellosolve solution of paradium chloride (PdCl <sub>2</sub> /conc.	38 parts by weight
15	hydrochloric acid/methyl cellosolve = 1/10/1000) 10% methyl cellosolve solution of 4-morpholino-2,5-dibutoxybenzene diazonium borofluoride (DH300BF, available from Daito Kagaku, Japan)	10 parts by weight

The photosensitive material layer thus formed was then brought into close contact with the mask surface of a photomask wherein lines, in which dots having a length of 15 micrometers and a width of 5 micrometers were lined at a pitch of 15 micrometers were negatively patterned in the form of stitpse having a pitch of 20 micrometers. The whole was exposed for 10 seconds to an ultra-high pressure mercury varsor lamp (3 kW; distance of one meter) from the photomask side. The photomask pattern used herein was obtained by photo etching method. This was done in such a manner that a Cr thin layer was provided on a glass plate by means of sputtering followed by applying photomask value from Shipley) thereon to be dried. Onto the dried surface was irradiated He-Cd laser at a beam diameter of 2 micrometers on a position controlled XY stage thereby to form lines, in which dots having a length of 15 micrometers and a width of 5 micrometers were lined at a pitch of 15 micrometers have an advanced of 20 micrometers. The product thus obtained was treated with a photoresist developing solution (Shipley) to be subjected to heat treatment at 130 °C for 25 minutes followed by ectaining with ferric chloride solution to obtain a pattern wherein the dotted portons functioned as light transmissive portions.

The patiern exposed photosensitive material layer thus obtained was immersed into the treating solution (A) described in Example 1 and the following solution (B) in order of from A to B respectively for 60 and 80 minutes (at a treating temperature of 30 °C).

(B) 3:2:1 Mixture of TMP Non-Ammonium Chemical Nickel A. TMP Non-Ammonium Chemical Nickel B and Water.

Nickel sulfate	8.0 grams
Sodium hypophosphite	5.5 grams
Sodium hydroxide	1.0 grams
Sodium citrate	3.5 grams
Water	82.0 grams
Water	82.0 grams

The immersed product was thereafter subjected to water rinsing and drying to obtain a first recording layer which had a black positive pattern corresponding to light transmissive portions and light creening portions.

On the recording layer thus patterned was applied a Te-Cu-Pb alloy (sputter target compositional ratio of a molar ratio of 80:15:5) by means of sputtering method to obtain a light recording material wherein a second recording layer was formed. In this case, the Te-Cu-Pb thin layer was not formed at the peripheral portions of the recording layer.

A card substrate was prepared as follows: First, a white rigid polyvinyl chloride (a thickness of 200 micrometers) was provided on both the sides thereof with a pattern such as character or design by screen printing method. Another transparent rigid polyvinyl chloride (A thickness of 100 micrometers) was provided on the single surface thereof with a magnetic recording layer with a width of 6.5 mm. The other surface thereof was laminated on the above printed white polyvinyl chloride to be subjected to hot pressing at 140 °C for 30 minutes between two sheets of stahless steel under a press machine so as to obtain a card

#### substrate.

The optical information carrier and card substrate respectively thus prepared were laminated in such a manner that the second recording layer of the optical information carrier faced the surface (printed side) of white polyinyli choride of the card substrate with urethane resin adhesives (mixture of Arbon EU-4200 and EHU4200 of a ratio of 10:1 available from Alps Kagaku Sangyo, Japan) interposed therebetween, thereby to be subjected to roller pressing. The pressed product was rested for 24 hours and then cut by means of a cutting die to obtain an optical card.

### Example 26

On a pattermed first recording layer which was obtained similarly as Example 25, a melamine type resin (Tough cost of 112 available from Del Nippon ink Kagakur Kopyo, Japan) was applied to be subjected to heat treatment at 120 °C for 3 minutes to form a barrier layer (a thickness of 3 micrometers). On the barrier layer thus formed was formed a second recording layer by sputtering a Te-Cu-Pb alloy (sputter target rs compositional ratio of a moter ratio of 80:155) to obtain an optical information carrier. In this case, the Te-Cu-Pb alloy of the second layer.

A card substrate was then prepared similarly as in Example 25. The prepared card was bonded to the above optical information carrier with adhesive interposed therebetween and subjected to curing and died to obtain an optical card.

### Example 27

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An optical information carrier and a card substrate were prepared similarly as in Example 25 except that an effective metallic thin layer was formed by metallizing aluminum on a patterned recording layer so that the thickness of aluminum might become 150 nm. In this case, the aluminum layer was not formed at the perioheral cortices of the recording layer.

The optical information carrier and card substrate respectively thus prepared were laminated in such a manner that the second recording layer of the optical information carrier faced the surface (printed side) of the properties of a substrate with urethane resin adhesives (mixtures of Arbon EU-4200 and 20 EH-4200 of a ratio of 101, available from Apis Kagaku Sangyo, Japan) interposed therebewheren, thereby to be subjected to roller pressing. The pressed product was rested for 24 hours and then cut by means of a cutting die to obtain an obtaical card.

#### Example 28

On a patterned recording layer obtained similarly as in Example 25, metamine resin (Tough coat 112 available from Dal Mippon Ink Kagaku Kogyo, Japan) was applied by bar coating method to be subjected to heat treatment at 120°C for 3 minutes to obtain a barier layer (a thickness of 3 micromaters). Aluminum was then metallized on the barrier layer so that the thickness of aluminum layer might become 150 nm, whereby a reflective metallic thin layer formed to obtain an optical information carrier. In this case, the aluminum layer was not formed at the peripheral portions of the recordinal layer.

A card substrate was prepared similarly as in Example 25. The card substrate thus prepared was laminated to the above optical information carrier by the use of adhesives to be subjected to curing followed by die cutting to obtain an optical card.

### Claims

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- An optical information carrier (1) comprising:
- (a) a substrate (2),

(b) a recording layer (5) provided on said substrate (2), said recording layer (5) consisting of light transmissive portions (3) and light screening portions (4), wherein readout of information written in said recording layer (5) is carried out by irradiating the optical information carrier (1) with a record playback light from the recording layer-free side of the substrate (2), and

(c) a reflective thin film layer (6) provided on said recording layer (5),

characterized in that

(d) said recording layer (5) is a first recording layer and sald thin film layer (6) is a second recording layer capable of writing information by and storing information after irradiating it with an energy beam, and

(e) said thin film layer (6) being the second recording layer having recording pits formed therein.

- The optical information carrier (1) according to claim 1, characterized in that
- said recording layer (5) comprises a photosensitive material containing
  - (a) a transparent resin as a binder.
  - (b) a photodecomposable development restrainer having a diazo or azido group, and
  - (c) a metal complex compound or a metal compound which is reduced to form metallic nuclei.
- The optical information carrier (1) according to claim 1, characterized in that

said thin film layer (6) is a metallic thin film layer composed of a metal or alloy selected from the group consisting of Te, Zn, Pb, Cd, Bi, Sn, Se, In, Ga, Rb, Te-Se, Te-Se-Pb, Te-Pb, Te-Sn-S, Sn-Cu, Te-Cu and Te-Cu-Pb.

- The optical information carrier (1) according to claim 1.
  - characterized in that

said thin film layer (6) is a metallic thin film layer composed of a metal selected from the group consisting of Al, Cr, Ni, Ag and Au.

- 5. The optical information carrier (1) according to claim 1.
- characterized in that

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said thin film layer (6) is composed of a multilayer film selected from the group consisting of In/Te and SiC<sub>A</sub>/T/SiC<sub>2</sub>/A), or of composite material selected from the group consisting of Te-CH<sub>4</sub>, Te-CS<sub>2</sub>, Te-styrene, Sn-So. GaS-Sn and SnS-S.

- The optical information carrier (1) according to claim 1, characterized in that
- said thin film layer (6) is a thin film obtained by cohering a dyestulf, by dispersing the dyestulf or metal particles in thermosetting resins or by adhering the dyestulf or metal particles to the surface of said resins.
- The optical information carrier (1) according to claim 1, characterized in that
- said thin film layer (6) is composed of a compound selected from the group consisting of Te oxide, Sb oxide, Mo oxide, Ge oxide V oxide, Sm oxide, Te oxide and Te-Sn.
  - The optical information carrier (1) according to claim 1, characterized in that
- said thin film layer (6) is composed of a material selected from the group consisting of chalcogen, color formation type McO<sub>3</sub>-Cu and McO<sub>3</sub>-Sn-Cu.
  - 9. The optical information carrier (1) according to claim 1,
  - characterized in that
- said thin film layer (6) is composed of a optomagnetic information carrier selected from the group consisting of GdCo, TbCo, GdFe, DyFe, GdTbFe, GdFeBi, TbDyFe and MnCuBi.
  - The optical information carrier (1) according to claim 5, characterized in that
- said metal compound which is reduced to form metallic nuclei is a compound of a metal selected from the group consisting of Pd, Au, Ag, Pt and Cu.
  - The optical information carrier (1) according to claim 10, characterized in that
- said metal compound is palladium chloride.
  - 12. A process for preparing an optical information carrier according to claim 1; comprising the steps of:

(a) applying onto a substrate a photosensitive material wherein any one of unexposed portions and exposed portions exhibits light transmission properties and the other exhibits light screening properties;

(b) then imagewise exposing the substrate provided with the photosensitive material; developing it to form a first recording layer:

(c) and thereafter forming a reflective metallic thin film layer on said recording layer, characterized in that

(d) the reflective thin film layer is formed as a second recording layer and thereafter it is irradiated with an energy beam to provide recording spots.

# 13. The process according to claim 12,

characterized in that

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In forming said first recording layer, an aqueous solution containing both of a water-soluble reducible metallic sait and a reducing agent is employed as a physical developing solution.

### 14. The process according to claim 13.

characterized in that

said reducible metallic saft is a water-soluble salt of a metal selected from the group consisting of Ni, Co, Fe, Cr, and Cu.

#### 15. The process according to claim 14.

characterized in that

said metallic salt is one member selected from the group consisting of halide, sulfate, and nitrate of a metal selected from the group consisting of NI, Co, Fe, Cr, and Cu.

# 16. The process according to claim 15,

characterized in that

said metallic salt is a water-soluble salt of Ni.

# 30 17. Optical card, characterized in that

it comprises an optical information carrier according to any one of claims 1 to 11.

# Patentansprüche

### ss 1. Optischer Informationsträger (1) aufweisend:

(a) ein Substrat (2),

(b) eine auf dem Substrat (2) vorgesehene Aufzelchnungsschicht (5), die besteht aus Lichtdurchlaßbereichen (3) und Lichtabschirmbereichen (4), wobei des Auslesen von in der Aufzeichnungsschichte (5) aufgazeichneten Information durchgeführt wird durch Bestratien des optischen Informationsträgers (1) mit einem Aufzeichnungs-Ausleselicht von der aufzeichnungsschichtfreien Seite des Sub-

strats (2) her, und (c) eine auf der Aufzeichnungsschicht (5) vorgesehene reflektierende dünne Filmschicht (6),

#### dadurch gekennzeichnet, daß

(e) die d\u00fcnne Filmschicht (6) die zweite Aufzeichnungsschicht ist mit darin ausgebildeten Aufzeichnungsvertiefungen.

### 2. Optischer Informationsträger (1) nach Anspruch 1,

dadurch gekennzeichnet, daß

die Aufzeichnungsschicht (5) ein lichtempfindliches Material aufweist, welches enthält

(a) ein transparentes Harz als ein Bindemittel.

(b) einen lichtzersetzbaren Entwicklungsverzögerer mit einer Diazo- oder Azido-Gruppe, und (c) eine Metalkomplex-Verbindung oder eine Metallverbindung, die zur Bildung metallischer Kerne reduziert wird.

3. Optischer Informationsträger (1) nach Anspruch (1),

dadurch gekennzeichnet, daß

die dünne Filmschicht (6) eine metallische, dünne Filmschicht ist, die zusammengesetzt Ist aus einem Metall oder einer Legierung, ausgewählt aus der aus Te, Zn, Pb, Cd, Bl, Sn, Se, In, Ga, Rb, Te-Se, Te-Se-Pb, Te-Pb, Te-Sn-S, Sn-Cu, Te-Cu und Te-Cu-Pb bestehenden Gruppe.

4. Optischer Informationsträger (1) nach Ansgruch 1.

dadurch gekennzeichnet, daß

die dünne Filmschicht (6) eine metallische, dünne Filmschicht ist, die zusammengesetzt ist aus einem Metall, das ausgewählt ist aus der aus Al. Cr. Ni. Ag und Au bestehenden Gruppe.

5. Optischer Informationsträger (1) nach Anspruch 1,

dadurch gekennzeichnet, daß

dle dünne Filmschicht (6) zusammengesetzt ist aus einem Vielschicht-Film, ausgewählt aus der aus In/Te und SiOz/Ti/SiOz/A) bestehenden Gruppe, oder aus einem Kompositmaterial, ausgewählt aus der aus Te-CHt, Te-CSz, Te-Styrol, Sn-SOz, GeS-Sn und SnS-S bestehenden Gruppe.

6. Optischer Informationsträger (1) nach Anspruch 1,

dadurch gekennzeichnet, daß

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die dünne Filmschicht (6) ein dünner Film ist, der erhalten wurde durch Anhängen eines Farbstoffs, durch Dispergieren des Farbstoffs oder von Metalitelichen in wärmehärtbaren Harzen oder durch Anhaften des Farbstoffs oder von Metalitelichen an die Oberttäche des Harzes.

7. Optischer Informationsträger (1) nach Anspruch 1,

dadurch gekennzeichnet, daß

die dünne Filmschicht (6) zusammengesetzt ist aus einer Verbindung, die ausgewählt ist aus der Gruppe, die besteht aus Te-Oxid, Sb-Oxid, Mo-Oxid, Ge-Oxid, V-Oxid, Sm-Oxid, Te-Oxid und Te-Sn.

8. Optischer Informationsträger (1) nach Anspruch 1,

dadurch gekennzelchnet, daß

die dünne Filmschicht (6) zusammengesetzt ist aus einem Material, das ausgewählt ist aus der Gruppe, die besteht aus Chalkogen, MoO<sub>2</sub>-Cu und MoO<sub>2</sub>-Sn-Cu vom farbbildenden Typ.

9. Optischer Informationsträger (1) nach Anspruch 1,

dadurch gekennzeichnet, daß

die dünne Filmschicht (6) zusammengesetzt ist aus einem optomagnetischen Informationsträger, der ausgewählt ist aus der Gruppe, die besteht aus GdCo, TbCo, GdFe, DyFe, GdTbFe, GdFeBI, TbDyFe und MnCuBI.

40 10. Optischer informationsträger (1) nach Anspruch 5,

dadurch gekennzelchnet, daß

die Metalliverbindung, die zur Bildung metallischer Kerne reduziert wird, eine Verbindung eines Metalles ist, daß ausgewählt ist aus der aus Pd. Au. Ao. Pt und Cu bestehenden Gruppe.

45 11. Optischer Informationsträger (1) nach Anspruch 10,

dadurch gekennzeichnet, daß

die Metallverbindung Palladiumchlorid ist.

12. Verfahren zur Herstellung eines optischen Informationsträgers gemaß Anspruch 1, folgende Schritte aufweisend:

(a) Aufringen eines Lichtempfindlichen Materials, bei dem entweder die nicht belichteten Bereiche oder die belichteten Bereiche Lichtduchlaß-Eigenschaften zeigen und die jeweils anderen Lichtabschlimeigenschaften zeigen, auf ein Substrat:

(b) dann bildweises Belichten des mit dem lichtempfindlichen Material versehenen Substrats; Entwickeln des lichtempfindlichen Materials zur Bildung einer ersten Aufzeichnungsschicht;

(c) und danach Ausbilden einer reflektierenden, metallischen, dünnen Filmschicht auf der Aufzelchnungsschicht,

dadurch gekennzeichnet, daß

(d) die reflektierende, d\u00fcnne Filmschicht als eine zweite Aufzeichnungsschicht ausgebildet ist und daß sie danach zur Schaffung von Aufzeichnungsstellen mit einem Energiestrahl bestrahlt wird.

### Verfahren nach Anspruch 12,

dadurch gekennzeichnet, daß

beim Ausbilden der ersten Aufzeichnungsschicht als eine physikalische Entwicklungstösung eine wässrige Lösung verwendet wird, die sowohl ein wasserlösliches, reduzierbares Metalisalz als auch ein Reduktionsmittel enthält.

### to 14. Verfahren nach Anspruch 13.

dadurch gekennzelchnet, daß

das reduzierbare Metallsalz ein wasserlösliches Salz eines Metalls ist, das ausgewählt ist aus der aus Ni. Co. Fe. Cr und Cu bestehenden Gruppe.

### 15. Verfahren nach Anspruch 14,

dadurch gekennzeichnet, daß

das Metallsalz ein Glied ist, das ausgewählt ist aus der Gruppe, die besteht aus Halogenid, Sulfat und Nitrat eines Metalls, das ausgewählt ist aus der Gruppe, die besteht aus Ni, Co, Fe, Cr und Cu.

### 20 16. Verfahren nach Anspruch 15,

dadurch gekennzeichnet, daß

das Metallsalz ein wasserlösliches Ni-Salz ist.

### 17. Optische Karte, dadurch gekennzeichnet, daß

sie einen optischen informationsträger gemäß irgendeinem der Ansprüche 1 bis 11 aufweist.

#### Revendications

1. Support d'information optique (1) comprenant :

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(b) une couche d'enregistrement (5) sur ledit support (2), ladite couche d'enregistrement (5) consistent en portions transmettant la lumière (3) et en portions faisant deran à la lumière (4), où la lecture de l'information inscrité dans ladite couche d'enregistrement (5) est effectée en irradiant le support d'information (1) avec une lumière de reproduction d'enregistrement depuis le côté du

as support (2) sans couche d'enregistrement et

(c) une couche réfléchissante en pellicule mince (6) sur ladite couche d'enregistrement (5),

caractérisé en ce que

(a) un support (2).

(d) ladite couche d'enregistrement (5) est une première couche d'enregistrement et ladite couche en pellicule mince (6) est une seconde couche d'enregistrement permetitant d'inscrire une information par irradiation avec un faisceau d'énergie et de stocker l'information après irradiation, et

(e) des alvéoles d'enregistrement sont formées dans ladite couche en pellicule mince (6) qui est la seconde couche d'enregistrement.

 Support d'information optique (1) selon la revendication 1, caractérisé en ce que ladite couche d'enregistrement (5) comprend une matière photosensible contenant

(a) une résine transparente comme llant,

(b) un retardateur de développement photodécomposable avant un groupe diazo ou azido, et

(c) un composé complexe métallique ou un composé métallique qui est réduit pour former des germes métalliques.

 Support d'information optique (1) selon la revendication 1, caractérisé en ce que ladite couche en pellicule mince (6) est une couche métallique en pellicule mince composée d'un métal ou alliage choisi parmi Te, Zn, Pb, Cd, Bl, Sn, Se, In, Ga, Rb, Te-Se, Te-Se-Pb, Te-Pb, Te-Sn-S, Sn-Cu, Te-Cu et Te-Cu-Pb.

 Support d'information optique (1) selon la revendication 1, caractérisé en ce que ladite couche en pellicule mince (6) est une couche métallique en pellicule mince composée d'un métal choisi parmi Al, Cr, NI, Ag et Au.

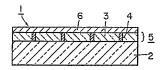
- Support d'information optique (1) selon la revendication 1, caractérsé en ce que ladite couche en pellicule à plusieurs couches choise parmi In/Te et al. SIC<sub>2</sub>/T/SIC<sub>2</sub>/M, ou un matériau composite choisi parmi Te-CH<sub>4</sub>, Te-CS<sub>2</sub>, Te-styrène, Sn-SO<sub>2</sub>, GeS-Sn et Sn-Sn.
- 6. Support d'information optique (1) selon la revendication 1, caractérisé en ce que ladite couche en pellicule mince (6) est une pellicule mince obtenue en agglomérant un colorant, en dispersant le colorant ou les particules métalliques dans des résines thermodurcissables ou en collant le colorant ou les particules métalliques à la surface desdites résines.
- Support d'information optique (1) seion la revendication 1, caractérisé en ce que ladite couche en pellicule mince (8) est composée d'un composé choisi parmi les suivants: oxyde de Te, oxyde de Sb, oxyde de Mo, oxyde de Ge, oxyde de V, oxyde de Sm, oxyde ab Te et Te-Sn.
- Support d'information optique (1) selon la revendication 1, caractérisé en ce que ladite couche en pellicule mince (6) est composée d'un matériau choisi parmi les chalcogènes, MoO<sub>2</sub>-Cu du type à formation de couleur et MoO-Sn-Cu.
- Support d'information optique (1) selon la revendication 1, caractérisé en ce que ladite couche en pellicule mince (6) est composée d'un support d'information optomagnétique choisi parmi GdCo, TbCo, GdFe, DyFe, GdTPFe, GdFeBi. TbDVFe et MnGuBi.
  - 10. Support d'information optique (1) selon la revendication 5, caractérisé en ce que ledit composé métallique qui est réduit pour former des germes métalliques est un composé d'un métal choisi parmi Pd, Au, Ag, Pt et Cu.
  - 11. Support d'information optique (1) selon la revendication 10, caractérisé en ce que ledit composé métallique est le chlorure de palfadium.
- 30 12. Procédé pour préparer un support d'information optique selon la revendication 1, comprenant les étapes suivantes :
  - (a) on applique sur un support une matière photosensible dans laquelle les portions non exposées ou les portions exposées présentent des propriétés de transmission de la lumière et les autres présentent des propriétés d'écran à la lumière;
- 35 (b) on expose ensuite suivant une image le support muni de la matière photosensible ; on le développe pour former une première couche d'enregistrement ; et ensuite
  - (c) on forme sur ladite couche d'enregistrement une couche en pellicule mince métallique réfléchissante,
  - caractérisé en ce que

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- (d) la couche en pellicule mince réfléchissante est formée comme seconde couche réfléchissante et ensuite elle est irradiée avec un faisceau d'énergie pour donner des points d'enregistrement.
- 13. Procédé selon la revendication 12, caractérisé en ce que, dans la formation de ladite première couche d'enregistement, on utilise comme solution de développement physique une solution aqueuse contenant à la fois un sol métallique réducible soluble dans l'eau et un agent réducteur.
- 14. Procédé selon la revendication 13, caractérisé en ce que ledit sel métallique réductible est un sel soluble dans l'eau d'un métal choisi parmi Ni. Co. Fe. Cr et Cu.
- 50 15. Procédé selon la revendication 14, caractérisé en ce que ledit sel métallique est un sel choisi parmi les halogénures, les sulfates et les nitrates d'un métal choisi parmi Ni, Co, Fe, Cr et Cu.
  - Procédé selon la revendication 15, caractérisé en ce que ledit sel métallique est un sel de Ni soluble dans l'eau.
  - Carte optique, caractérisée en ce qu'elle comprend un support d'information optique selon l'une quelconque des revendications 1 à 11.

FIG. I



F1G.2

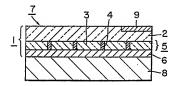
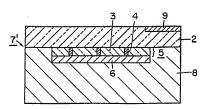


FIG. 3





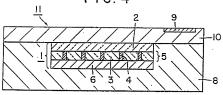


FIG.5

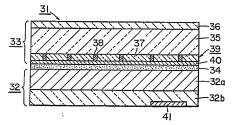


FIG. 6

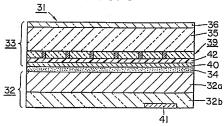


FIG. 7

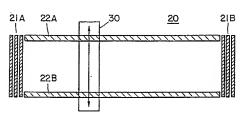


FIG. 8

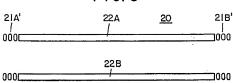


FIG. 9

